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(54) Method and apparatus for terahertz imaging

(57) Certain material and objects can be characterized by a frequency-dependent absorption, dispersion, and reflection of terahertz transients in signals which pass illuminate the material or object. The present terahertz imaging system analyses that frequency dependence in the time-domain by collecting that transmitted signal propagating through the object and then processing the information contained in those signals for every point or "pixel" on that object. This is a non-invasive imaging technique that is capable of differentiating between different materials, chemical compositions, or environments.

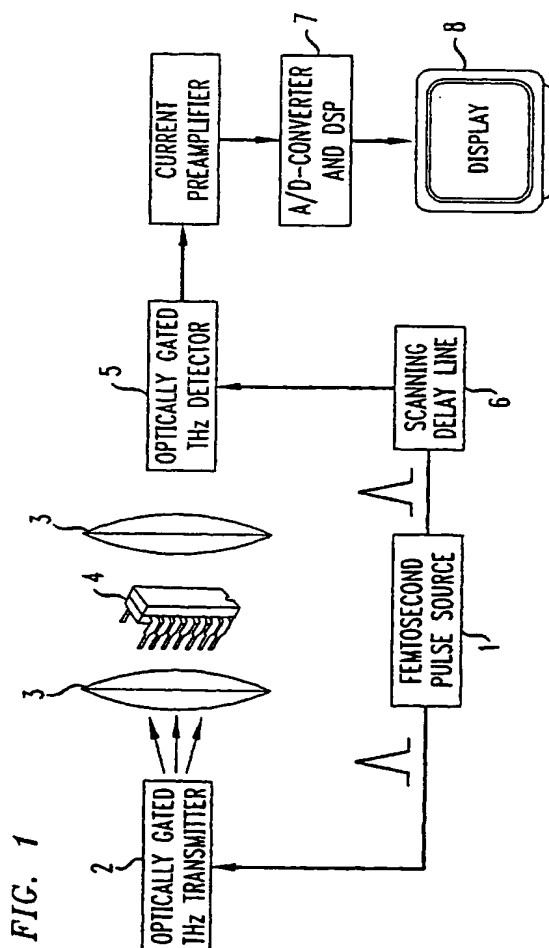


FIG. 1



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EUROPEAN SEARCH REPORT

Application Number
EP 96 30 0828

DOCUMENTS CONSIDERED TO BE RELEVANT			
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int.Cl.6)
P,X	OPTICS LETTERS, vol. 20, no. 16, 15 August 1995, pages 1716-1718, 1718A, XP000520882 HU B B AND NUSS M C: "IMAGING WITH TERAHERTZ WAVES" * the whole document *	1-5	G01R31/265 G01N21/35
A	JOURNAL OF THE OPTICAL SOCIETY OF AMERICA - B, vol. 7, no. 10, 1 October 1990, pages 2006-2015, XP000570771 GRISCHKOWSKY D ET AL: "FAR-INFRARED TIME-DOMAIN SPECTROSCOPY WITH TERAHERTZ BEAMS OF DIELECTRICS AND SEMICONDUCTORS" * abstract; figure 1 *	1	
A	JAPANESE JOURNAL OF APPLIED PHYSICS, vol. 24, no. 11, 1985, pages 1565-1566, XP002022314 TSUGURU S ET AL: "PHOTOLUMINESCENCE MEASUREMENT IN GAAS WITH HIGH SPATIAL RESOLUTION"		TECHNICAL FIELDS SEARCHED (Int.Cl.6)
D,A	APPLIED PHYSICS LETTERS, vol. 58, no. 3, 21 January 1991, pages 222-224, XP000208483 KATZENELLENBOGEN N ET AL: "EFFICIENT GENERATION OF 380 FS PULSES OF THZ RADIATION BY ULTRAFAST LASER PULSE EXCITATION OF A BIASED METAL-SEMICONDUCTOR INTERFACE"		G01N G01R
The present search report has been drawn up for all claims			
Place of search THE HAGUE		Date of completion of the search 8 January 1997	Examiner Tabellion, M
<p>CATEGORY OF CITED DOCUMENTS</p> <p>X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document</p> <p>T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons & : member of the same patent family, corresponding document</p>			

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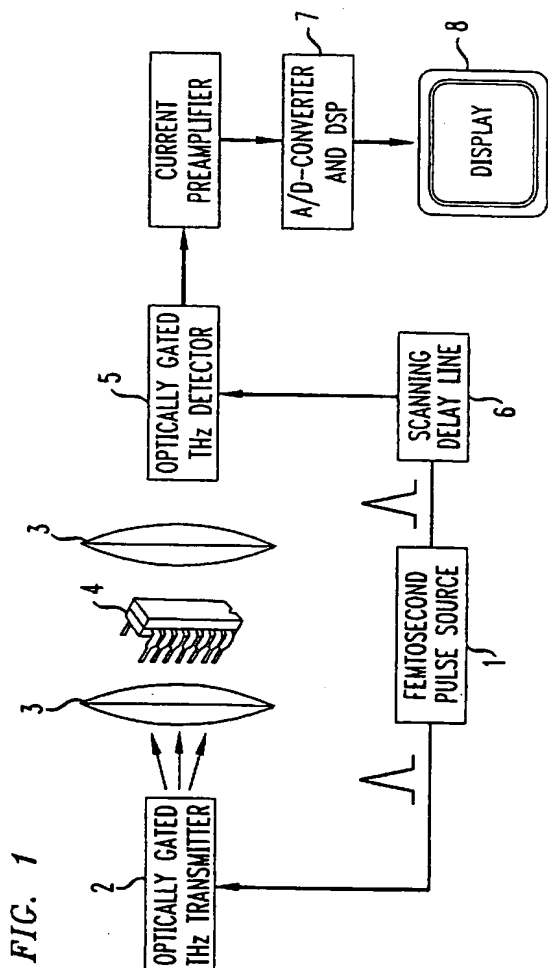


FIG. 1

Description

Technical Field

This invention relates to spectroscopy in the terahertz frequency range and, more particularly, to a method and apparatus for creating images of objects with signals in this frequency range.

Background of the Invention

Terahertz time-domain spectroscopy ("THz-TDS") is a very powerful spectroscopic technique in the far-infrared spectral region. Terahertz radiation has been generated and detected using optically gated transmitters and receivers such as photoconducting dipole antennae as described in P. Smith et al., *IEEE J. of Quantum Electronics*, Vol. 24, No. 2, pp. 255-260 (1988) and N. Katzenellenbogen et al., *Appl. Phys. Lett.*, Vol. 58, No. 3, pp. 222-224 (1991). With these techniques, terahertz spectroscopy offers a reasonably good signal-to-noise ratio (up to approximately 10^4); it can be performed without special thermal stabilization apparatus such as cooled detectors; it can be realized in a compact system; and it offers a transmitter and detector technology which is compatible with integrated circuit technology.

Numerous experiments using terahertz time domain spectroscopy have been performed on solids, liquids, and gases. Some experiments have analyzed the spectrum of a terahertz signal affected by carriers in semiconductors and superconductors. Other experiments have performed terahertz time domain spectroscopy on water vapor as well as N_2O gas. Still other experiments have reported terahertz time domain spectroscopy of chemical compounds in the liquid phase. In all these experiments, the terahertz signal was transmitted through the object under study in a single illuminated volume region (usually 25 mm in diameter) to provide the spectral information about that homogeneous region.

Summary of the Invention

I have recognized that the time domain spectroscopy and, more particularly, terahertz signals can be used for imaging objects by collecting individual signals propagating through distinct (spatially separate) points on the object and processing these signals to create the image of the object. It is also possible to focus the signal source on the object at distinct points and scan the source and detector in synchronism across the object in a pattern transverse to the propagation direction. Additionally, it is possible to cause the source to bathe the entire object with substantially parallel beams which could then be sampled by a detector scanning the object. Of course, in an alternative embodiment it would be possible to translate the object in the appropriate

transverse directions while holding the focused transmitter and receiver in substantially fixed positions.

Brief Description of the Drawing

A more complete understanding of the invention may be obtained by reading the following description of specific illustrative embodiments of the invention in conjunction with the appended drawing in which:

FIG. 1 shows a simplified block diagram of an illustrative terahertz imaging system in accordance with the principles of the present invention;

FIGs. 2 and 3 show comparisons between input terahertz waveforms and the output waveform after propagating through a known material;

FIGs. 4 through 6 show illustrative embodiments for insuring a desired amount of scanning for the object to be scanned by the system of FIG. 1;

FIG. 7 shows a portion of an illustrative terahertz focal plane array useful in the embodiment in FIG. 6; and

FIG. 8 shows an image of a semiconductor dual-inline packaged chip produced by the illustrated terahertz imaging system.

Detailed Description

The THz imaging system of FIG. 1 in accordance with the present invention includes a source 1 of repetitive, femtosecond duration, optical pulses, an optically gated transmitter 2 of THz transients having a broad spectral bandwidth, imaging optics 3 comprising lenses and/or mirrors, an object 4 to be investigated, a time-gated detector or detector array 5, a scanning delay 6 capable of changing the delay between the femtosecond gating pulses on the transmitter and detector(s) at a rate of a few Hz to hundreds of Hz for the purpose of temporally heterodyning the THz-frequency transients down into the acoustic (Hz) range so that they can be processed by electronic techniques, a digital signal processing unit 7 including a digital signal processor and an A/D converter to process the time-domain data and extract the desired information, and a display 8 to view the image.

Certain material and objects can be characterized by a frequency-dependent absorption, dispersion, and reflection of terahertz transients in signals which pass through the material or object. The present terahertz imaging system analyses that frequency dependence in the time-domain by collecting that transmitted signal propagating through the object and then processing the information contained in those signals for every point or "pixel" on that object. This is a non-invasive imaging technique that is capable of differentiating between different materials, chemical compositions, or environments. This technique has applications not solely limited to biomedical imaging of tissue, "safe X-rays", chemical

reaction analysis, environmental and pollution control, process control, materials inspection, fault detection, non-contact mapping of the doping in semiconductor wafers, profiling of doping and defects in laser crystals, and packaging inspection.

A typical terahertz transmitter emits a single cycle of electromagnetic radiation centered at 1 THz after being illuminated by a 100 fs laser pulse from either a mode-locked dye laser operating around 620 nm or a mode-locked Ti:Sapphire or Cr:LiSAF laser operating around 800 nm. Because of the short duration of the THz-transient, the spectrum is broadband, typically extending from less than 100 GHz to several THz.

No electronic circuit is capable of measuring and processing THz bandwidth electrical signals directly at this time. Sampling techniques based on the repetitive nature (typically ≈ 100 MHz repetition rate) of the optical and THz pulses can be used to measure the THz waveforms provided that the sampling window is shorter than any THz transient to be measured. Typical photoconducting sampling gates have sampling times shorter than 0.5 ps and are thus able to measure frequency transients in excess of 2 THz. No fast electronics is needed in the sampling technique, and only the average photocurrent in the dipole antenna is measured. Similar to a sampling scope, the delay between the THz waveform and the detector gating pulse is scanned slowly at a rate of about 10-100 Hz. Thus, each sampling pulse samples the THz pulse at a somewhat different time, until the entire THz waveform has been reconstructed from the samples. This leads to a "temporal down conversion" of the THz waveform into the kHz range, where it can readily be processed by electronics. This sampling technique is also known as Equivalent-Time-Sampling but is otherwise used in any commercial digital sampling oscilloscope. This isochronous sampling technique has been described for picosecond optical sampling by K. Weingarten et al. in *IEEE J. of Quantum Electronics*, Vol. 24, No. 2, pp. 198-220 (1988).

Many, if not most, compounds show very strong frequency-dependent absorption or reflection within the frequency range covered by these THz transients. Also, molecules and chemical compounds, at least in the gas phase, but also ions in certain crystals, have strong and sharp absorption lines in the THz spectral regions. The absorption lines are characteristic of the material under study such as a water molecule and its environment and can serve as a "fingerprint" of the molecule. Each chemical substance hence leads to a characteristic THz waveform that identifies the chemical composition and environment of the sample. There are also materials that are completely opaque to THz radiation such as metals and other materials with high electrical conductivity.

In the present THz imaging system, the spectra described above need not be computed or directly measured. Instead, the relevant information can be extracted right from the time-domain data, in a manner similar to

speech recognition and processing. In FIGs. 2 and 3 are the input THz waveforms (dashed) and the waveforms after propagation through the doped silicon sample (FIG. 2) and water vapor (FIG. 3).

The digital signal processor can recognize the characteristic shapes of the transmitted THz waveforms (specific shape change and attenuation in one case for silicon and ringing with characteristic frequency in the other case for water vapor), to determine the particular material at the spot illuminated by the THz beam. This requires training (or loading) the DSP with these specific waveforms in advance. Such a procedure is well within the knowledge of persons skilled in the art and will not be repeated here.

In a particular embodiment shown in FIG. 4 for the transmitter, receiver, and optics of FIG. 1, the THz beam emerging from the transmitter is focused to a diffraction-limited spot of 0.3-0.5 mm diameter. This is the diffraction-limited spot size for 1 THz radiation and close to the best spatial resolution possible with this technique. This spot is then imaged onto a single THz detector. The sample is placed in the focal plane of the THz beam and scanned in x and y in a zigzag pattern using two orthogonal, motor driven translation stages (shown pictorially by the x and y arrows).

The delay between transmitter and detector gating pulses is continuously scanned by a 10 Hz scanning delay line. The amplitude of the scanning delay line can be adjusted and determines the time window of data acquisition - a 1 mm amplitude corresponds to a 6.7 ps time window. The average photocurrent induced in the photoconducting dipole detector is measured with a current-to-voltage converter and then fed to a A/D-converter and DSP processor card. We use an A/D-converter capable of a 50 kHz conversion rate, and a DSP processor that can Fourier-transform the waveforms at a rate of 100 FFTs each second. Thus, with this system we can easily obtain the FFT spectrum of each THz waveform synchronously with the 10 Hz scan rate.

In an example from practice, the FFT spectrum is represented on the display screen as a colored dot with the frequency components of the THz spectrum represented by the frequencies of the visible (rainbow) spectrum. That is, the terahertz spectrum is mapped onto the visible spectrum and only those frequency components which propagate through the object under study can contribute to the displayed color.

Since DSPs are used in this system, it is also possible to utilize time domain techniques by computing the convolution (correlation) between the received terahertz signals and stored patterns which are related to particular elements, compounds, etc. The signals which most closely match the received signals will identify the point of the object being scanned.

In another example from experimental practice, the DSP processor looks for certain absorption lines which are characteristic of a specific molecule and assigns a specific color and intensity to this absorption pattern. Af-

ter each scan, the sample is moved by one "pixel" (preferably roughly the spot size of the THz beam on the sample) and the display is updated for that particular pixel. With the above system, a 50x50 image can be acquired and displayed in just over 4 minutes.

FIG. 8 shows a preliminary result for a THz image obtained as described above. The picture is a so-called "THz X-Ray" of a packaged semiconductor chip.

In another embodiment shown in FIG. 5 for the transmitter, receiver, and optics of the imaging system in FIG. 1, the sample remains stationary and the THz beams are scanned across the sample. This can be done either by mechanically steering the THz beam with mirrors or by optical steering of the THz beam (in which case, steering of the optical beams causes a steering of the THz beams).

In the embodiment shown in FIG. 6 for the transmitter, receiver, and optics of the imaging system in FIG. 1, THz waveforms for the entire sample are acquired simultaneously by using a focal-plane THz detector array as shown in FIG. 7. Here, the entire sample is flood-illuminated by a THz beam, and the sample is imaged onto the focal-plane detector array using a lens system. The flood-illumination causes the illumination to appear as parallel beams from individual point sources.

The focal plane THz detector array consists of a two-dimensional array of THz dipole antennas (in this case 50 μm on each side) which are lithographically defined on a low temperature (LT)-GaAs or radiation-damaged Silicon-on-Sapphire (SOS) chip so that the gating time is subpicosecond. MSM photoconductive switches using interdigitated finger contacts are defined between the antenna chip. The size of the interdigitated photoconductive MSM switch is roughly 10 μm square. Each of the antenna/MSM elements constitutes a THz image pixel. The MSM photoconductive switches are gated by a short optical pulse derived from a beam that covers the entire area of the chip and is focused onto the MSM detectors using a microlens array. The microlens array and the gate pulse can either come from the same side as the THz radiation (with a beam splitter), or from opposite sides (in this case the THz beam travels through the chip substrates before it is detected by the antennas). Only 1 pJ of readout energy is required for each MSM gate, so that a 10 nJ optical pulse can gate a 100x100 focal plane array. The antenna chip is solder bump-bonded to another chip underneath with one contact on each antenna pad that carries the detected photocurrent off the chip and to the DSP processor. Preferably, the underlying chip contacted by the solder bumps is a CCD array, so that all pixels can be read out sequentially like a video camera. The photogenerated charges are accumulated in the CCD array over many optical pulses before the charge is read out.

Claims

1. A method of imaging an object CHARACTERIZED BY the steps of:

transmitting a sequence of high speed pulse signals at a particular point on said object, detecting said signals after propagation through said object, translating said object to cause said signals to pass through a plurality of spatially distinct areas on said object, and analyzing spectral information in the time domain to create an image of said object, said information contained in the received signals.

2. The method as defined in claim 1 wherein the step of analyzing includes identifying a composition characteristic of the object at the particular point.
3. The method as defined in claim 2 wherein said signals are in the range of frequencies from 100 GHz to 20 THz.

4. Apparatus for imaging an object CHARACTERIZED BY,

a source of high speed pulse signals, imaging optics for causing said signals to be focused on a particular area of said object, a detector for receiving said signals after propagation through said object, means for translating said object to cause said signals to pass through a plurality of spatially distinct areas on said object, and means coupled to said detector for analyzing spectral information in the time domain to create an image of said object, said information contained in the received pulse signals.

5. The apparatus as defined in claim 4 wherein the means for analyzing further includes means for identifying a composition characteristic of the object at the particular point.

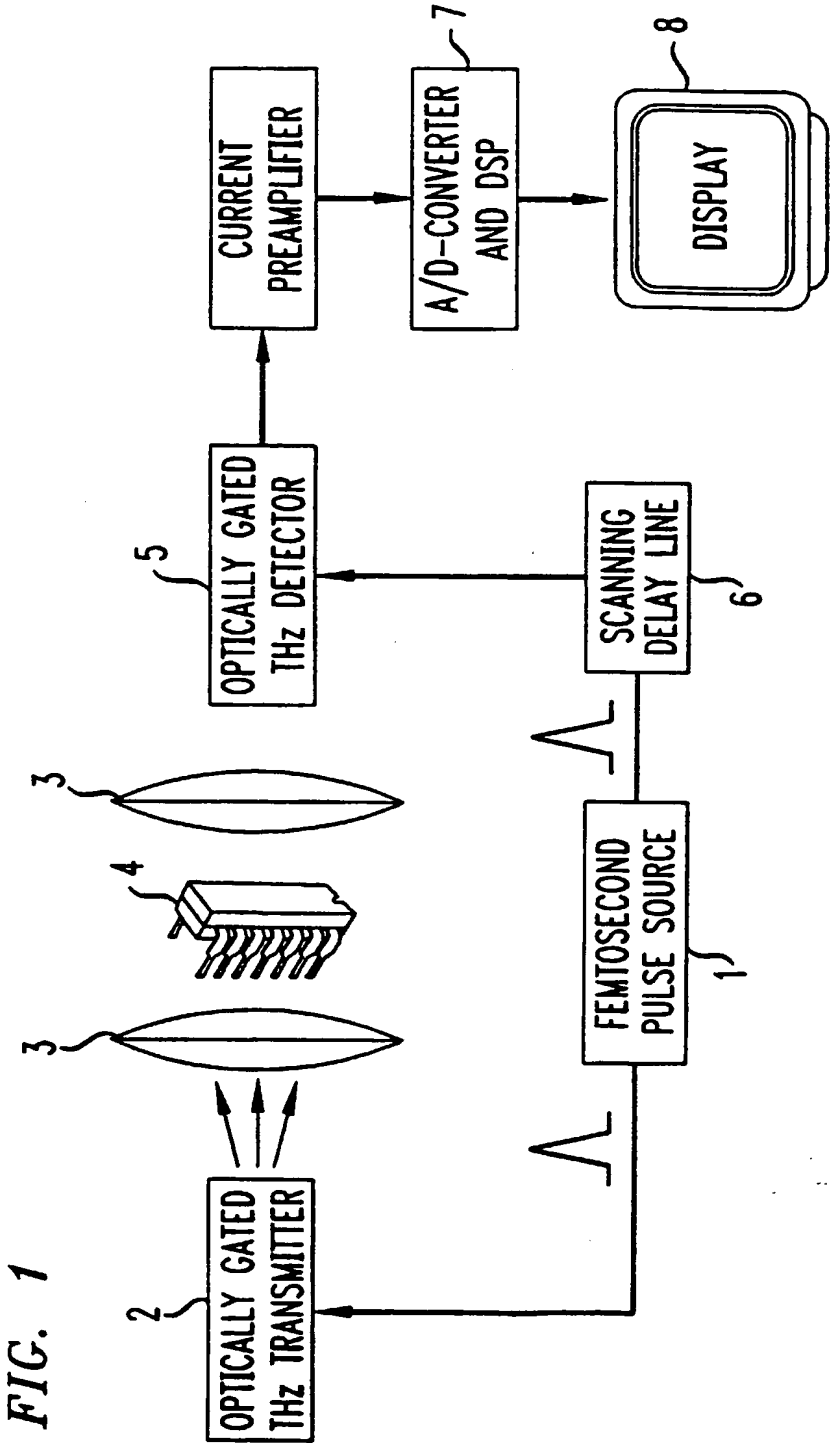


FIG. 2

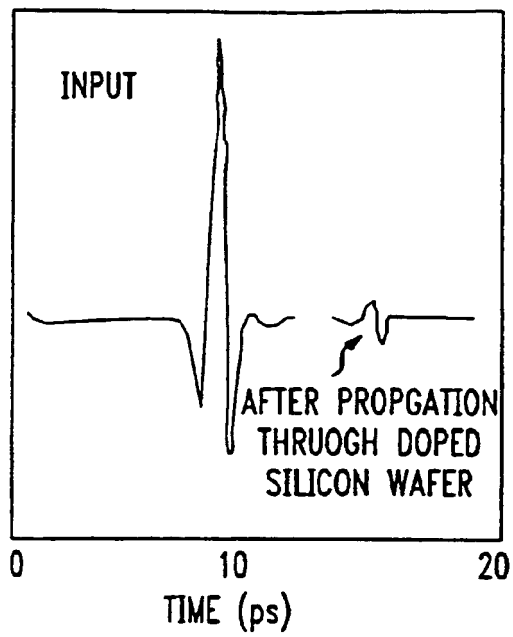


FIG. 3

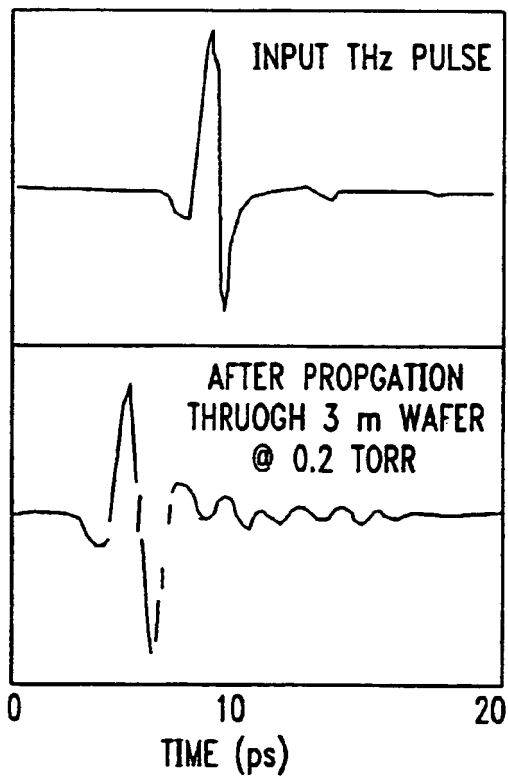


FIG. 4

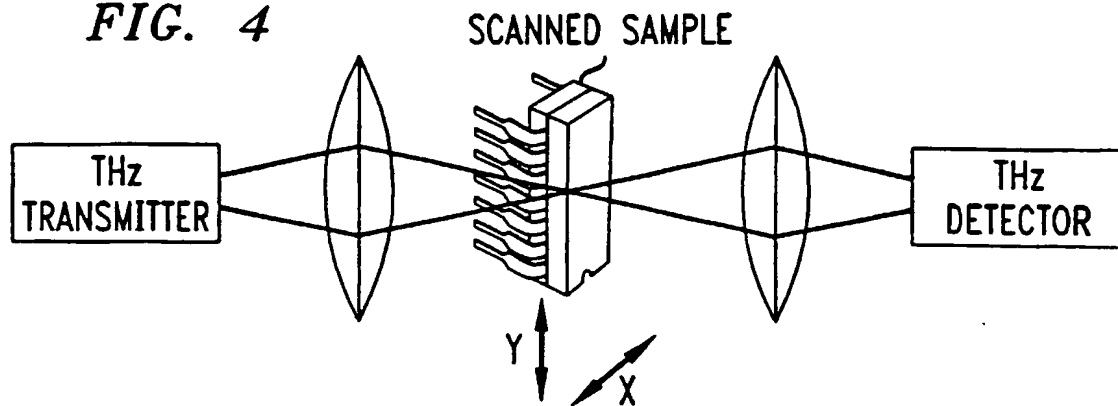


FIG. 5

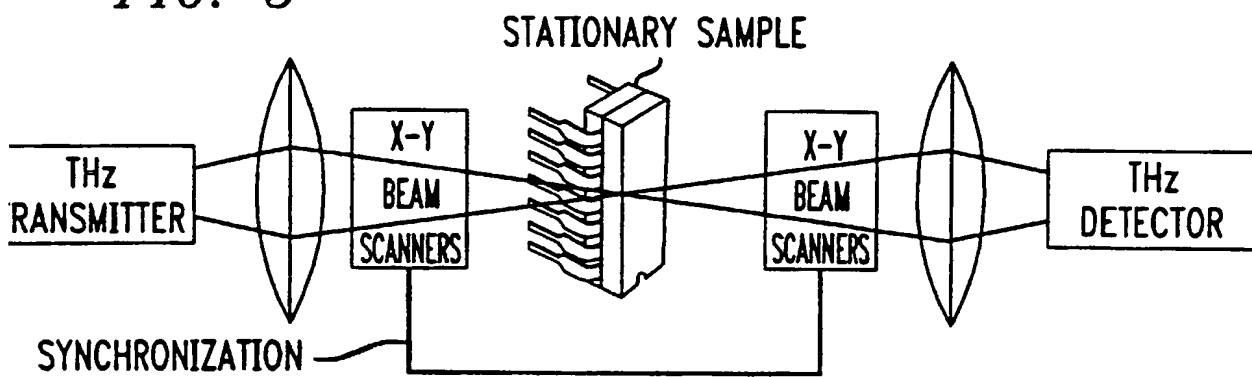


FIG. 6

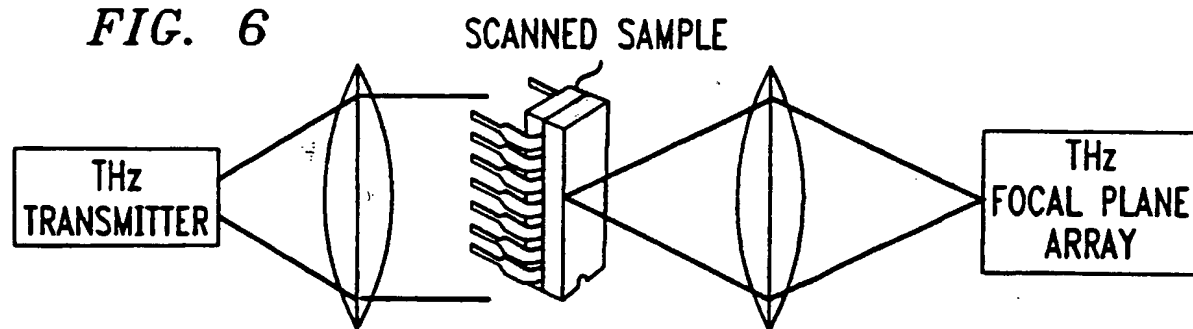


FIG. 7

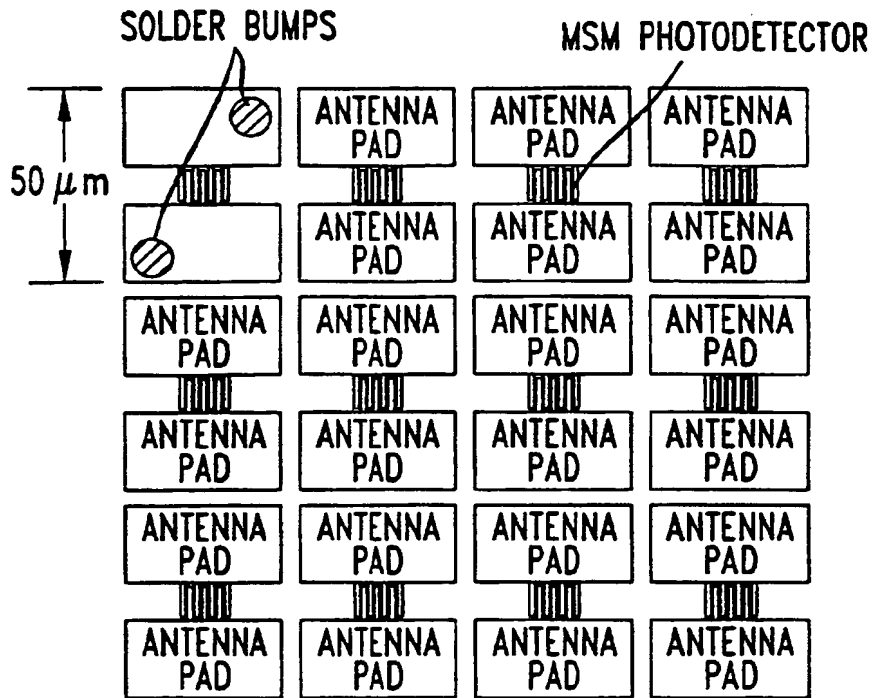
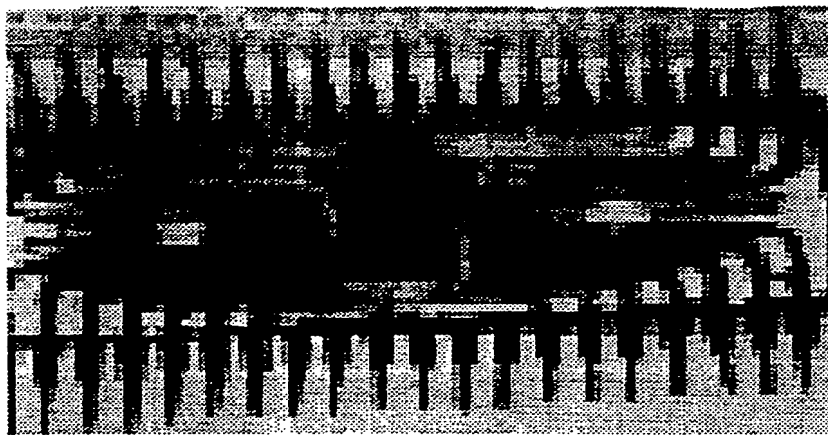


FIG. 8



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